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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details

Product Status	Active
Number of LABs/CLBs	1164
Number of Logic Elements/Cells	10476
Total RAM Bits	368640
Number of I/O	92
Number of Gates	500000
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	132-TFBGA, CSPBGA
Supplier Device Package	132-CSPBGA (8x8)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xc3s500e-4cpg132i

Spartan-3E FPGAs provide additional input flexibility by allowing I/O standards to be mixed in different banks. For a particular V_{CCO} voltage, Table 6 and Table 7 list all of the

IOSTANDARDS that can be combined and if the IOSTANDARD is supported as an input only or can be used for both inputs and outputs.

Table 6: Single-Ended IOSTANDARD Bank Compatibility

Single-Ended IOSTANDARD	V_{CCO} Supply/Compatibility					Input Requirements	
	1.2V	1.5V	1.8V	2.5V	3.3V	V_{REF}	Board Termination Voltage (V_{TT})
LVTTTL	-	-	-	-	Input/Output	N/R ⁽¹⁾	N/R
LVC MOS33	-	-	-	-	Input/Output	N/R	N/R
LVC MOS25	-	-	-	Input/Output	Input	N/R	N/R
LVC MOS18	-	-	Input/Output	Input	Input	N/R	N/R
LVC MOS15	-	Input/Output	Input	Input	Input	N/R	N/R
LVC MOS12	Input/Output	Input	Input	Input	Input	N/R	N/R
PCI33_3	-	-	-	-	Input/Output	N/R	N/R
PCI66_3	-	-	-	-	Input/Output	N/R	N/R
HSTL_I_18	-	-	Input/Output	Input	Input	0.9	0.9
HSTL_III_18	-	-	Input/Output	Input	Input	1.1	1.8
SSTL18_I	-	-	Input/Output	Input	Input	0.9	0.9
SSTL2_I	-	-	-	Input/Output	Input	1.25	1.25

Notes:

1. N/R - Not required for input operation.

The SLICEM pair supports two additional functions:

- Two 16x1 distributed RAM blocks, RAM16
- Two 16-bit shift registers, SRL16

Each of these elements is described in more detail in the following sections.

Logic Cells

The combination of a LUT and a storage element is known as a “Logic Cell”. The additional features in a slice, such as the wide multiplexers, carry logic, and arithmetic gates, add to the capacity of a slice, implementing logic that would otherwise require additional LUTs. Benchmarks have shown that the overall slice is equivalent to 2.25 simple logic cells. This calculation provides the equivalent logic cell count shown in [Table 9](#).

Slice Details

[Figure 15](#) is a detailed diagram of the SLICEM. It represents a superset of the elements and connections to be found in all slices. The dashed and gray lines (blue when viewed in color) indicate the resources found only in the SLICEM and not in the SLICEL.

Each slice has two halves, which are differentiated as top and bottom to keep them distinct from the upper and lower slices in a CLB. The control inputs for the clock (CLK), Clock

Enable (CE), Slice Write Enable (SLICEWE1), and Reset/Set (RS) are shared in common between the two halves.

The LUTs located in the top and bottom portions of the slice are referred to as “G” and “F”, respectively, or the “G-LUT” and the “F-LUT”. The storage elements in the top and bottom portions of the slice are called FFY and FFX, respectively.

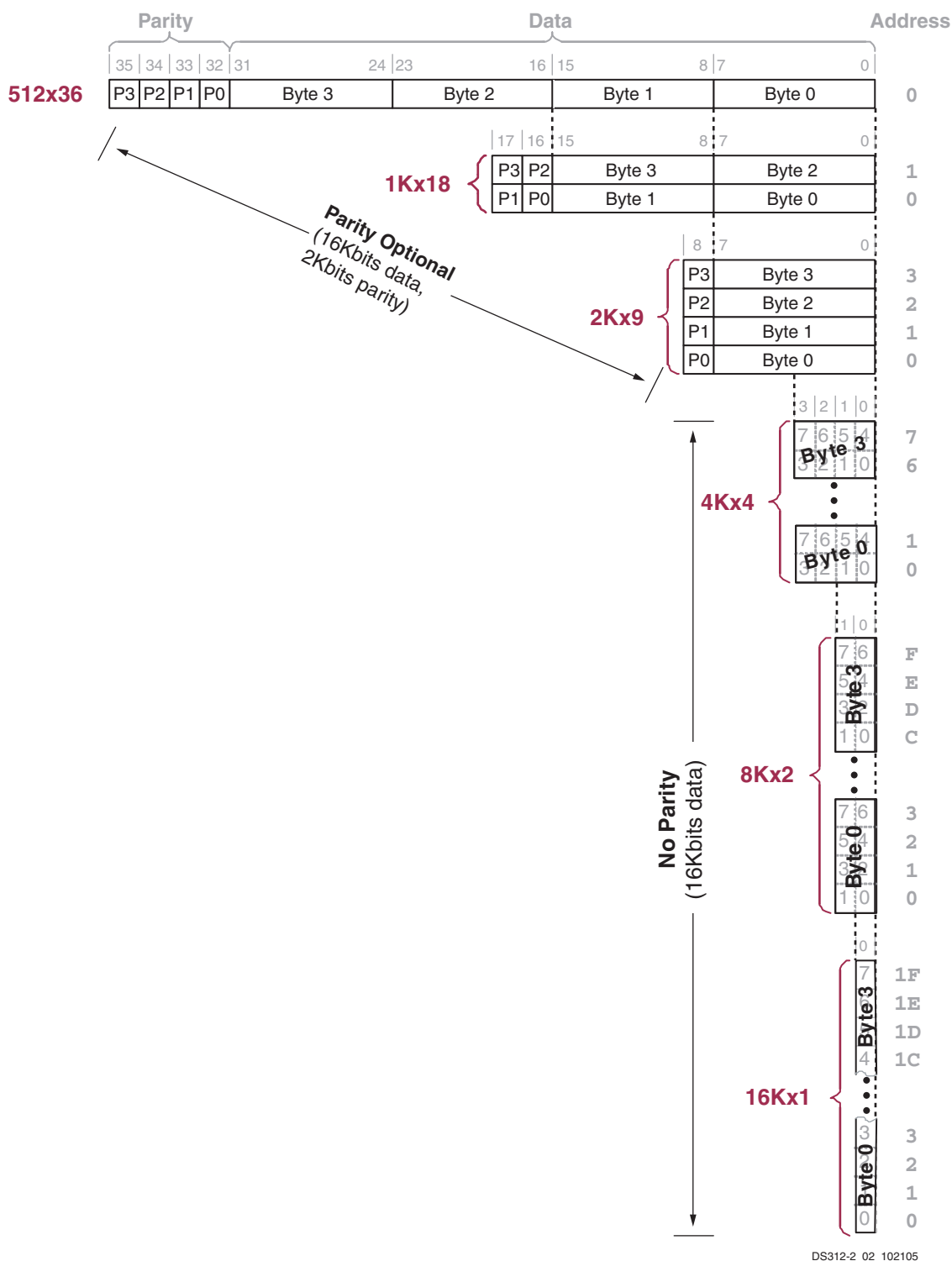
Each slice has two multiplexers with F5MUX in the bottom portion of the slice and FiMUX in the top portion. Depending on the slice, the FiMUX takes on the name F6MUX, F7MUX, or F8MUX, according to its position in the multiplexer chain. The lower SLICEL and SLICEM both have an F6MUX. The upper SLICEM has an F7MUX, and the upper SLICEL has an F8MUX.

The carry chain enters the bottom of the slice as CIN and exits at the top as COUT. Five multiplexers control the chain: CYINIT, CY0F, and CYMUXF in the bottom portion and CY0G and CYMUXG in the top portion. The dedicated arithmetic logic includes the exclusive-OR gates XORF and XORG (bottom and top portions of the slice, respectively) as well as the AND gates FAND and GAND (bottom and top portions, respectively).

See [Table 10](#) for a description of all the slice input and output signals.

Table 10: Slice Inputs and Outputs

Name	Location	Direction	Description
F[4:1]	SLICEL/M Bottom	Input	F-LUT and FAND inputs
G[4:1]	SLICEL/M Top	Input	G-LUT and GAND inputs or Write Address (SLICEM)
BX	SLICEL/M Bottom	Input	Bypass to or output (SLICEM) or storage element, or control input to F5MUX, input to carry logic, or data input to RAM (SLICEM)
BY	SLICEL/M Top	Input	Bypass to or output (SLICEM) or storage element, or control input to FiMUX, input to carry logic, or data input to RAM (SLICEM)
BXOUT	SLICEM Bottom	Output	BX bypass output
BYOUT	SLICEM Top	Output	BY bypass output
ALTDIG	SLICEM Top	Input	Alternate data input to RAM
DIG	SLICEM Top	Output	ALTDIG or SHIFTIN bypass output
SLICEWE1	SLICEM Common	Input	RAM Write Enable
F5	SLICEL/M Bottom	Output	Output from F5MUX; direct feedback to FiMUX
FXINA	SLICEL/M Top	Input	Input to FiMUX; direct feedback from F5MUX or another FiMUX
FXINB	SLICEL/M Top	Input	Input to FiMUX; direct feedback from F5MUX or another FiMUX
Fi	SLICEL/M Top	Output	Output from FiMUX; direct feedback to another FiMUX
CE	SLICEL/M Common	Input	FFX/Y Clock Enable
SR	SLICEL/M Common	Input	FFX/Y Set or Reset or RAM Write Enable (SLICEM)
CLK	SLICEL/M Common	Input	FFX/Y Clock or RAM Clock (SLICEM)
SHIFTIN	SLICEM Top	Input	Data input to G-LUT RAM



DS312-2_02_102105

Figure 31: Data Organization and Bus-matching Operation with Different Port Widths on Port A and Port B

Table 23: Block RAM Port Signals

Signal Description	Port A Signal Name	Port B Signal Name	Direction	Function
Address Bus	ADDRA	ADDRB	Input	The Address Bus selects a memory location for read or write operations. The width (w) of the port's associated data path determines the number of available address lines (r), as per Table 22 . Whenever a port is enabled (ENA or ENB = High), address transitions must meet the data sheet setup and hold times with respect to the port clock (CLKA or CLKB), as shown in Table 103, page 138 . This requirement must be met even if the RAM read output is of no interest.
Data Input Bus	DIA	DIB	Input	Data at the DI input bus is written to the RAM location specified by the address input bus (ADDR) during the active edge of the CLK input, when the clock enable (EN) and write enable (WE) inputs are active. It is possible to configure a port's DI input bus width (w-p) based on Table 22 . This selection applies to both the DI and DO paths of a given port.
Parity Data Input(s)	DIPA	DIPB	Input	Parity inputs represent additional bits included in the data input path. Although referred to herein as "parity" bits, the parity inputs and outputs have no special functionality for generating or checking parity and can be used as additional data bits. The number of parity bits 'p' included in the DI (same as for the DO bus) depends on a port's total data path width (w). See Table 22 .
Data Output Bus	DOA	DOB	Output	Data is written to the DO output bus from the RAM location specified by the address input bus, ADDR. See the DI signal description for DO port width configurations. Basic data access occurs on the active edge of the CLK when WE is inactive and EN is active. The DO outputs mirror the data stored in the address ADDR memory location. Data access with WE active if the WRITE_MODE attribute is set to the value: WRITE_FIRST , which accesses data after the write takes place. READ_FIRST accesses data before the write occurs. A third attribute, NO_CHANGE , latches the DO outputs upon the assertion of WE. See Block RAM Data Operations for details on the WRITE_MODE attribute.
Parity Data Output(s)	DOPA	DOPB	Output	Parity outputs represent additional bits included in the data input path. The number of parity bits 'p' included in the DI bus (same as for the DO bus) depends on a port's total data path width (w). See the DIP signal description for configuration details.
Write Enable	WEA	WEB	Input	When asserted together with EN, this input enables the writing of data to the RAM. When WE is inactive with EN asserted, read operations are still possible. In this case, a latch passes data from the addressed memory location to the DO outputs.
Clock Enable	ENA	ENB	Input	When asserted, this input enables the CLK signal to perform read and write operations to the block RAM. When inactive, the block RAM does not perform any read or write operations.
Set/Reset	SSRA	SSRB	Input	When asserted, this pin forces the DO output latch to the value of the SRVAL attribute. It is synchronized to the CLK signal.
Clock	CLKA	CLKB	Input	This input accepts the clock signal to which read and write operations are synchronized. All associated port inputs are required to meet setup times with respect to the clock signal's active edge. The data output bus responds after a clock-to-out delay referenced to the clock signal's active edge.

There are a number of different conditions under which data can be accessed at the DO outputs. Basic data access always occurs when the WE input is inactive. Under this condition, data stored in the memory location addressed by the ADDR lines passes through a output latch to the DO outputs. The timing for basic data access is shown in the

portions of [Figure 33](#), [Figure 34](#), and [Figure 35](#) during which WE is Low.

Data also can be accessed on the DO outputs when asserting the WE input based on the value of the [WRITE_MODE](#) attribute as described in [Table 26](#).

Table 26: **WRITE_MODE** Effect on Data Output Latches During Write Operations

Write Mode	Effect on Same Port	Effect on Opposite Port (dual-port only with same address)
WRITE_FIRST Read After Write	Data on DI and DIP inputs is written into specified RAM location and simultaneously appears on DO and DOP outputs.	Invalidates data on DO and DOP outputs.
READ_FIRST Read Before Write	Data from specified RAM location appears on DO and DOP outputs. Data on DI and DIP inputs is written into specified location.	Data from specified RAM location appears on DO and DOP outputs.
NO_CHANGE No Read on Write	Data on DO and DOP outputs remains unchanged. Data on DI and DIP inputs is written into specified location.	Invalidates data on DO and DOP outputs.

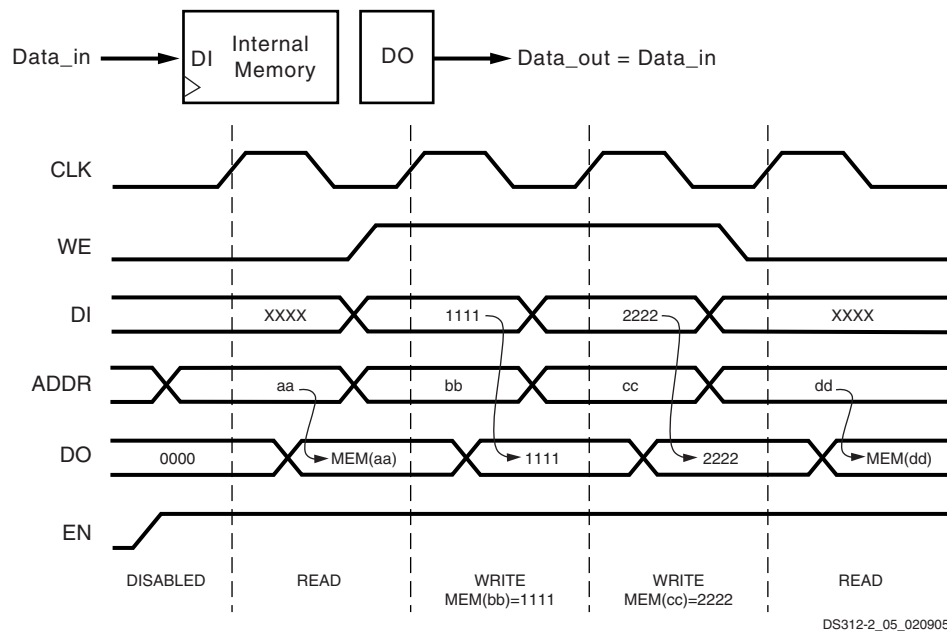


Figure 33: **Waveforms of Block RAM Data Operations with WRITE_FIRST Selected**

Setting the [WRITE_MODE](#) attribute to a value of [WRITE_FIRST](#), data is written to the addressed memory location on an enabled active CLK edge and is also passed to the DO outputs. [WRITE_FIRST](#) timing is shown in the portion of [Figure 33](#) during which WE is High.

Setting the [WRITE_MODE](#) attribute to a value of [READ_FIRST](#), data already stored in the addressed location passes to the DO outputs before that location is overwritten with new data from the DI inputs on an enabled active CLK edge. [READ_FIRST](#) timing is shown in the portion of [Figure 34](#) during which WE is High.

cancel out the clock skew. When the DLL phase-aligns the CLK0 signal with the CLKIN signal, it asserts the LOCKED output, indicating a lock on to the CLKIN signal.

DLL Attributes and Related Functions

The DLL unit has a variety of associated attributes as described in [Table 29](#). Each attribute is described in detail in the sections that follow.

Table 29: DLL Attributes

Attribute	Description	Values
CLK_FEEDBACK	Chooses either the CLK0 or CLK2X output to drive the CLKFB input	NONE, <u>1X</u> , 2X
CLKIN_DIVIDE_BY_2	Halves the frequency of the CLKIN signal just as it enters the DCM	<u>FALSE</u> , TRUE
CLKDV_DIVIDE	Selects the constant used to divide the CLKIN input frequency to generate the CLKDV output frequency	1.5, <u>2</u> , 2.5, 3, 3.5, 4, 4.5, 5, 5.5, 6.0, 6.5, 7.0, 7.5, 8, 9, 10, 11, 12, 13, 14, 15, and 16
CLKIN_PERIOD	Additional information that allows the DLL to operate with the most efficient lock time and the best jitter tolerance	Floating-point value representing the CLKIN period in nanoseconds

DLL Clock Input Connections

For best results, an external clock source enters the FPGA via a Global Clock Input (GCLK). Each specific DCM has four possible direct, optimal GCLK inputs that feed the DCM's CLKIN input, as shown in [Table 30](#). [Table 30](#) also provides the specific pin numbers by package for each GCLK input. The two additional DCM's on the XC3S1200E and XC3S1600E have similar optimal connections from the left-edge LHCLK and the right-edge RHCLK inputs, as described in [Table 31](#) and [Table 32](#).

- The DCM supports differential clock inputs (for example, LVDS, LVPECL_25) via a pair of GCLK inputs that feed an internal single-ended signal to the DCM's CLKIN input.

Design Note

Avoid using global clock input GCLK1 as it is always shared with the M2 mode select pin. Global clock inputs GCLK0, GCLK2, GCLK3, GCLK12, GCLK13, GCLK14, and GCLK15 have shared functionality in some configuration modes.

Direct Connections

Direct connect lines route signals to neighboring tiles: vertically, horizontally, and diagonally. These lines most often drive a signal from a “source” tile to a double, hex, or long line and conversely from the longer interconnect back to a direct line accessing a “destination” tile.

Global Controls (STARTUP_SPARTAN3E)

In addition to the general-purpose interconnect, Spartan-3E FPGAs have two global logic control signals, as described in [Table 43](#). These signals are available to the FPGA application via the STARTUP_SPARTAN3E primitive.

Table 43: Spartan-3E Global Logic Control Signals

Global Control Input	Description
GSR	Global Set/Reset: When High, asynchronously places all registers and flip-flops in their initial state (see Initialization, page 31). Asserted automatically during the FPGA configuration process (see Start-Up, page 105).
GTS	Global Three-State: When High, asynchronously forces all I/O pins to a high-impedance state (Hi-Z, three-state).

The Global Set/Reset (GSR) signal replaces the global reset signal included in many ASIC-style designs. Use the GSR control instead of a separate global reset signal in the design to free up CLB inputs, resulting in a smaller, more efficient design. Similarly, the GSR signal is asserted automatically during the FPGA configuration process, guaranteeing that the FPGA starts-up in a known state.

The STARTUP_SPARTAN3E primitive also includes two other signals used specifically during configuration. The MBT signals are for [Dynamically Loading Multiple Configuration Images Using MultiBoot Option, page 91](#). The CLK input is an alternate clock for configuration [Start-Up, page 105](#).

Configuration Bitstream Image Sizes

A specific Spartan-3E part type always requires a constant number of configuration bits, regardless of design complexity, as shown in [Table 45](#). The configuration file size for a multiple-FPGA daisy-chain design roughly equals the sum of the individual file sizes.

Table 45: Number of Bits to Program a Spartan-3E FPGA (Uncompressed Bitstreams)

Spartan-3E FPGA	Number of Configuration Bits
XC3S100E	581,344
XC3S250E	1,353,728
XC3S500E	2,270,208
XC3S1200E	3,841,184
XC3S1600E	5,969,696

Pin Behavior During Configuration

For additional information, refer to the “Configuration Pins and Behavior during Configuration” chapter in [UG332](#).

[Table 46](#) shows how various pins behave during the FPGA configuration process. The actual behavior depends on the

values applied to the M2, M1, and M0 mode select pins and the HSWAP pin. The mode select pins determine which of the I/O pins are borrowed during configuration and how they function. In JTAG configuration mode, no user-I/O pins are borrowed for configuration.

All user-I/O pins, input-only pins, and dual-purpose pins that are not actively involved in the currently-select configuration mode are high impedance (floating, three-stated, Hi-Z) during the configuration process. These pins are indicated in [Table 46](#) as gray shaded table entries or cells.

The HSWAP input controls whether all user-I/O pins, input-only pins, and dual-purpose pins have a pull-up resistor to the supply rail or not. When HSWAP is Low, each pin has an internal pull-up resistor that is active throughout configuration. After configuration, pull-up and pull-down resistors are available in the FPGA application as described in [Pull-Up and Pull-Down Resistors](#).

The yellow-shaded table entries or cells represent pins where the pull-up resistor is always enabled during configuration, regardless of the HSWAP input. The post-configuration behavior of these pins is defined by Bitstream Generator options as defined in [Table 69](#).

Table 46: Pin Behavior during Configuration

Pin Name	Master Serial	SPI (Serial Flash)	BPI (Parallel NOR Flash)	JTAG	Slave Parallel	Slave Serial	I/O Bank ⁽³⁾
IO* (user-I/O) IP* (input-only)							-
TDI	TDI	TDI	TDI	TDI	TDI	TDI	V _{CCAUX}
TMS	TMS	TMS	TMS	TMS	TMS	TMS	V _{CCAUX}
TCK	TCK	TCK	TCK	TCK	TCK	TCK	V _{CCAUX}
TDO	TDO	TDO	TDO	TDO	TDO	TDO	V _{CCAUX}
PROG_B	PROG_B	PROG_B	PROG_B	PROG_B	PROG_B	PROG_B	V _{CCAUX}
DONE	DONE	DONE	DONE	DONE	DONE	DONE	V _{CCAUX}
HSWAP	HSWAP	HSWAP	HSWAP	HSWAP	HSWAP	HSWAP	0
M2	0	0	0	1	1	1	2
M1	0	0	1	0	1	1	2
M0	0	1	0 = Up 1 = Down	1	0	1	2
CCLK	CCLK (I/O)	CCLK (I/O)	CCLK (I/O)		CCLK (I)	CCLK (I)	2
INIT_B	INIT_B	INIT_B	INIT_B		INIT_B	INIT_B	2
CSO_B		CSO_B	CSO_B		CSO_B		2
DOUT/BUSY	DOUT	DOUT	BUSY		BUSY	DOUT	2
MOSI/CSI_B		MOSI	CSI_B		CSI_B		2
D7			D7		D7		2
D6			D6		D6		2
D5			D5		D5		2
D4			D4		D4		2
D3			D3		D3		2
D2			D2		D2		2
D1			D1		D1		2

Ⓜ Table 54 shows the connections between the SPI Flash PROM and the FPGA's SPI configuration interface. Each SPI Flash PROM vendor uses slightly different signal naming. The SPI Flash PROM's write protect and hold

controls are not used by the FPGA during configuration. However, the $\overline{\text{HOLD}}$ pin must be High during the configuration process. The PROM's write protect input must be High in order to write or program the Flash memory.

Table 54: Example SPI Flash PROM Connections and Pin Naming

SPI Flash Pin	FPGA Connection	STMicro	NexFlash	Silicon Storage Technology	Atmel DataFlash
DATA_IN	MOSI	D	DI	SI	SI
DATA_OUT	DIN	Q	DO	SO	SO
$\overline{\text{SELECT}}$	CSO_B	$\overline{\text{S}}$	$\overline{\text{CS}}$	CE#	$\overline{\text{CS}}$
CLOCK	CCLK	C	CLK	SCK	SCK
$\overline{\text{WR_PROTECT}}$ Ⓜ	Not required for FPGA configuration. Must be High to program SPI Flash. Optional connection to FPGA user I/O after configuration.	$\overline{\text{W}}$	$\overline{\text{WP}}$	WP#	$\overline{\text{WP}}$
$\overline{\text{HOLD}}$ (see Figure 53)	Not required for FPGA configuration but must be High during configuration. Optional connection to FPGA user I/O after configuration. Not applicable to Atmel DataFlash.	$\overline{\text{HOLD}}$	$\overline{\text{HOLD}}$	HOLD#	N/A
$\overline{\text{RESET}}$ (see Figure 54)	Only applicable to Atmel DataFlash. Not required for FPGA configuration but must be High during configuration. Optional connection to FPGA user I/O after configuration. Do not connect to FPGA's PROG_B as this will prevent direct programming of the DataFlash.	N/A	N/A	N/A	$\overline{\text{RESET}}$
RDY/ $\overline{\text{BUSY}}$ (see Figure 54)	Only applicable to Atmel DataFlash and only available on certain packages. Not required for FPGA configuration. Output from DataFlash PROM. Optional connection to FPGA user I/O after configuration.	N/A	N/A	N/A	RDY/ $\overline{\text{BUSY}}$

The mode select pins, M[2:0], and the variant select pins, VS[2:0] are sampled when the FPGA's INIT_B output goes High and must be at defined logic levels during this time. After configuration, when the FPGA's DONE output goes High, these pins are all available as full-featured user-I/O pins.

Ⓟ Similarly, the FPGA's HSWAP pin must be Low to enable pull-up resistors on all user-I/O pins or High to

disable the pull-up resistors. The HSWAP control must remain at a constant logic level throughout FPGA configuration. After configuration, when the FPGA's DONE output goes High, the HSWAP pin is available as full-featured user-I/O pin and is powered by the VCCO_0 supply.

In a single-FPGA application, the FPGA's DOUT pin is not used but is actively driving during the configuration process.

Table 55: Serial Peripheral Interface (SPI) Connections

Pin Name	FPGA Direction	Description	During Configuration	After Configuration
HSWAP Ⓟ	Input	User I/O Pull-Up Control. When Low during configuration, enables pull-up resistors in all I/O pins to respective I/O bank V _{CCO} input. 0: Pull-ups during configuration 1: No pull-ups	Drive at valid logic level throughout configuration.	User I/O
M[2:0]	Input	Mode Select. Selects the FPGA configuration mode. See Design Considerations for the HSWAP, M[2:0], and VS[2:0] Pins .	M2 = 0, M1 = 0, M0 = 1. Sampled when INIT_B goes High.	User I/O

Single-Ended I/O Standards

Table 80: Recommended Operating Conditions for User I/Os Using Single-Ended Standards

IOSTANDARD Attribute	V _{CCO} for Drivers ⁽²⁾			V _{REF}			V _{IL}	V _{IH} ⁽³⁾
	Min (V)	Nom (V)	Max (V)	Min (V)	Nom (V)	Max (V)	Max (V)	Min (V)
LVTTL	3.0	3.3	3.465	V _{REF} is not used for these I/O standards			0.8	2.0
LVC MOS33 ⁽⁴⁾	3.0	3.3	3.465				0.8	2.0
LVC MOS25 ^(4,5)	2.3	2.5	2.7				0.7	1.7
LVC MOS18	1.65	1.8	1.95				0.4	0.8
LVC MOS15	1.4	1.5	1.6				0.4	0.8
LVC MOS12	1.1	1.2	1.3				0.4	0.7
PCI33_3 ⁽⁶⁾	3.0	3.3	3.465				0.3 • V _{CCO}	0.5 • V _{CCO}
PCI66_3 ⁽⁶⁾	3.0	3.3	3.465				0.3 • V _{CCO}	0.5 • V _{CCO}
HSTL_I_18	1.7	1.8	1.9	0.8	0.9	1.1	V _{REF} - 0.1	V _{REF} + 0.1
HSTL_III_18	1.7	1.8	1.9	-	1.1	-	V _{REF} - 0.1	V _{REF} + 0.1
SSTL18_I	1.7	1.8	1.9	0.833	0.900	0.969	V _{REF} - 0.125	V _{REF} + 0.125
SSTL2_I	2.3	2.5	2.7	1.15	1.25	1.35	V _{REF} - 0.125	V _{REF} + 0.125

Notes:

- Descriptions of the symbols used in this table are as follows:
V_{CCO} – the supply voltage for output drivers
V_{REF} – the reference voltage for setting the input switching threshold
V_{IL} – the input voltage that indicates a Low logic level
V_{IH} – the input voltage that indicates a High logic level
- The V_{CCO} rails supply only output drivers, not input circuits.
- For device operation, the maximum signal voltage (V_{IH} max) may be as high as V_{IN} max. See Table 73.
- There is approximately 100 mV of hysteresis on inputs using LVC MOS33 and LVC MOS25 I/O standards.
- All Dedicated pins (PROG_B, DONE, TCK, TDI, TDO, and TMS) use the LVC MOS25 standard and draw power from the V_{CCAUX} rail (2.5V). The Dual-Purpose configuration pins use the LVC MOS standard before the User mode. When using these pins as part of a standard 2.5V configuration interface, apply 2.5V to the V_{CCO} lines of Banks 0, 1, and 2 at power-on as well as throughout configuration.
- For information on PCI IP solutions, see www.xilinx.com/pci. The PCIX IOSTANDARD is available and has equivalent characteristics but no PCI-X IP is supported.

Differential I/O Standards

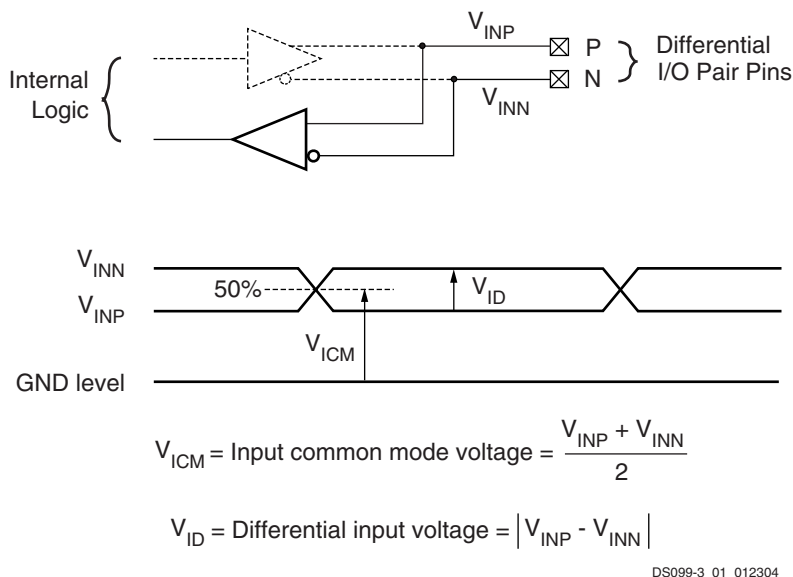


Figure 69: Differential Input Voltages

Table 82: Recommended Operating Conditions for User I/Os Using Differential Signal Standards

IOSTANDARD Attribute	V_{CCO} for Drivers ⁽¹⁾			V_{ID}			V_{ICM}		
	Min (V)	Nom (V)	Max (V)	Min (mV)	Nom (mV)	Max (mV)	Min (V)	Nom (V)	Max (V)
LVDS_25	2.375	2.50	2.625	100	350	600	0.30	1.25	2.20
BLVDS_25	2.375	2.50	2.625	100	350	600	0.30	1.25	2.20
MINI_LVDS_25	2.375	2.50	2.625	200	-	600	0.30	-	2.2
LVPECL_25 ⁽²⁾	Inputs Only			100	800	1000	0.5	1.2	2.0
RSDS_25	2.375	2.50	2.625	100	200	-	0.3	1.20	1.4
DIFF_HSTL_I_18	1.7	1.8	1.9	100	-	-	0.8	-	1.1
DIFF_HSTL_III_18	1.7	1.8	1.9	100	-	-	0.8	-	1.1
DIFF_SSTL18_I	1.7	1.8	1.9	100	-	-	0.7	-	1.1
DIFF_SSTL2_I	2.3	2.5	2.7	100	-	-	1.0	-	1.5

Notes:

1. The V_{CCO} rails supply only differential output drivers, not input circuits.
2. V_{REF} inputs are not used for any of the differential I/O standards.

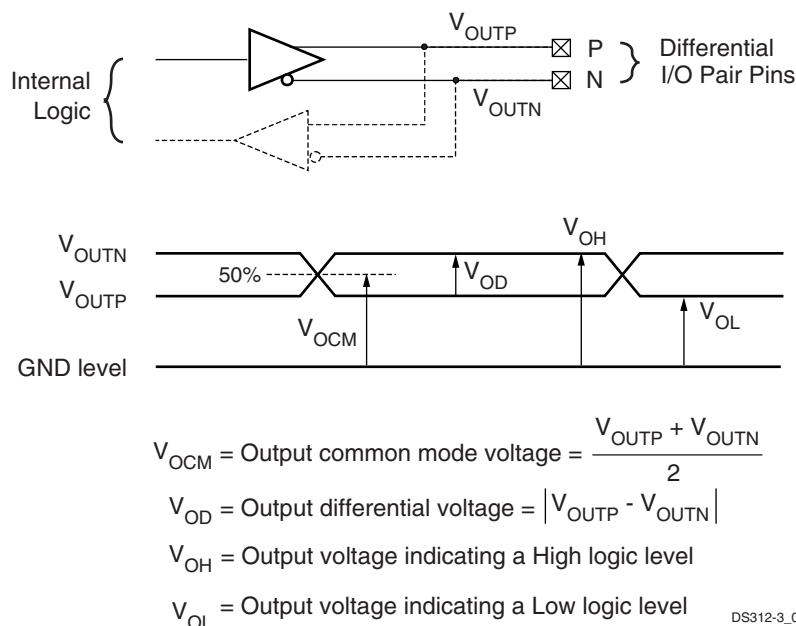


Figure 70: Differential Output Voltages

Table 83: DC Characteristics of User I/Os Using Differential Signal Standards

IOSTANDARD Attribute	V_{OD}			ΔV_{OD}		V_{OCM}			ΔV_{OCM}		V_{OH}	V_{OL}
	Min (mV)	Typ (mV)	Max (mV)	Min (mV)	Max (mV)	Min (V)	Typ (V)	Max (V)	Min (mV)	Max (mV)	Min (V)	Max (V)
LVDS_25	250	350	450	—	—	1.125	—	1.375	—	—	—	—
BLVDS_25	250	350	450	—	—	—	1.20	—	—	—	—	—
MINI_LVDS_25	300	—	600	—	50	1.0	—	1.4	—	50	—	—
RSDS_25	100	—	400	—	—	1.1	—	1.4	—	—	—	—
DIFF_HSTL_I_18	—	—	—	—	—	—	—	—	—	—	$V_{CCO} - 0.4$	0.4
DIFF_HSTL_III_18	—	—	—	—	—	—	—	—	—	—	$V_{CCO} - 0.4$	0.4
DIFF_SSTL18_I	—	—	—	—	—	—	—	—	—	—	$V_{TT} + 0.475$	$V_{TT} - 0.475$
DIFF_SSTL2_I	—	—	—	—	—	—	—	—	—	—	$V_{TT} + 0.61$	$V_{TT} - 0.61$

Notes:

1. The numbers in this table are based on the conditions set forth in Table 77 and Table 82.
2. Output voltage measurements for all differential standards are made with a termination resistor (R_T) of 100 Ω across the N and P pins of the differential signal pair. The exception is for BLVDS, shown in Figure 71.
3. At any given time, no more than two of the following differential output standards may be assigned to an I/O bank: LVDS_25, RSDS_25, MINI_LVDS_25

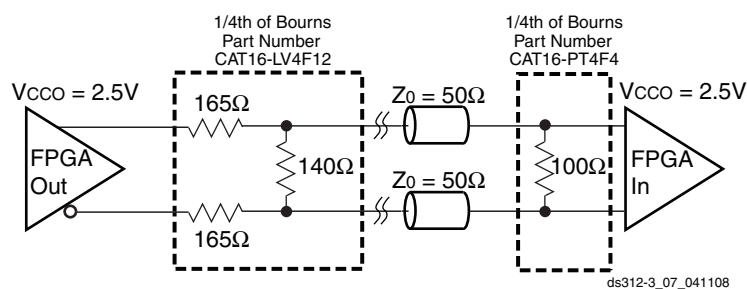


Figure 71: External Termination Resistors for BLVDS Transmitter and BLVDS Receiver

Table 92: Timing for the IOB Output Path

Symbol	Description	Conditions	Device	Speed Grade		Units
				-5	-4	
				Min	Min	
Clock-to-Output Times						
T _{IOCKP}	When reading from the Output Flip-Flop (OFF), the time from the active transition at the OCLK input to data appearing at the Output pin	LVC MOS25 ⁽²⁾ , 12 mA output drive, Fast slew rate	All	2.18	2.50	ns
Propagation Times						
T _{IOOP}	The time it takes for data to travel from the IOB's O input to the Output pin	LVC MOS25 ⁽²⁾ , 12 mA output drive, Fast slew rate	All	2.24	2.58	ns
T _{IOOLP}	The time it takes for data to travel from the O input through the OFF latch to the Output pin			2.32	2.67	ns
Set/Reset Times						
T _{IOSRP}	Time from asserting the OFF's SR input to setting/resetting data at the Output pin	LVC MOS25 ⁽²⁾ , 12 mA output drive, Fast slew rate	All	3.27	3.76	ns
T _{IOGSRQ}	Time from asserting the Global Set Reset (GSR) input on the STARTUP_SPARTAN3E primitive to setting/resetting data at the Output pin			8.40	9.65	ns

Notes:

1. The numbers in this table are tested using the methodology presented in [Table 95](#) and are based on the operating conditions set forth in [Table 77](#) and [Table 80](#).
2. This time requires adjustment whenever a signal standard other than LVC MOS25 with 12 mA drive and Fast slew rate is assigned to the data Output. When this is true, *add* the appropriate Output adjustment from [Table 94](#).
3. For minimum delays use the values reported by the Timing Analyzer.

Table 93: Timing for the IOB Three-State Path

Symbol	Description	Conditions	Device	Speed Grade		Units
				-5	-4	
				Max	Max	
Synchronous Output Enable/Disable Times						
T _{IOCKHZ}	Time from the active transition at the OTCLK input of the Three-state Flip-Flop (TFF) to when the Output pin enters the high-impedance state	LVCMOS25, 12 mA output drive, Fast slew rate	All	1.49	1.71	ns
T _{IOCKON} ⁽²⁾	Time from the active transition at TFF's OTCLK input to when the Output pin drives valid data		All	2.70	3.10	ns
Asynchronous Output Enable/Disable Times						
T _{GTS}	Time from asserting the Global Three State (GTS) input on the STARTUP_SPARTAN3E primitive to when the Output pin enters the high-impedance state	LVCMOS25, 12 mA output drive, Fast slew rate	All	8.52	9.79	ns
Set/Reset Times						
T _{IOSRHZ}	Time from asserting TFF's SR input to when the Output pin enters a high-impedance state	LVCMOS25, 12 mA output drive, Fast slew rate	All	2.11	2.43	ns
T _{IOSRON} ⁽²⁾	Time from asserting TFF's SR input at TFF to when the Output pin drives valid data		All	3.32	3.82	ns

Notes:

1. The numbers in this table are tested using the methodology presented in [Table 95](#) and are based on the operating conditions set forth in [Table 77](#) and [Table 80](#).
2. This time requires adjustment whenever a signal standard other than LVCMOS25 with 12 mA drive and Fast slew rate is assigned to the data Output. When this is true, *add* the appropriate Output adjustment from [Table 94](#).
3. For minimum delays use the values reported by the Timing Analyzer.

Revision History

The following table shows the revision history for this document.

Date	Version	Revision
03/01/05	1.0	Initial Xilinx release.
11/23/05	2.0	Added AC timing information and additional DC specifications.
03/22/06	3.0	Upgraded data sheet status to Preliminary. Finalized production timing parameters. All speed grades for all Spartan-3E FPGAs are now Production status using the v1.21 speed files, as shown in Table 84 . Expanded description in Note 2, Table 78 . Updated pin-to-pin and clock-to-output timing based on final characterization, shown in Table 86 . Updated system-synchronous input setup and hold times based on final characterization, shown in Table 87 and Table 88 . Updated other I/O timing in Table 90 . Provided input and output adjustments for LVPECL_25, DIFF_SSTL and DIFF_HSTL I/O standards that supersede the v1.21 speed file values, in Table 91 and Table 94 . Reduced I/O three-state and set/reset delays in Table 93 . Added XC3S100E FPGA in CP132 package to Table 96 . Increased T_{AS} slice flip-flop timing by 100 ps in Table 98 . Updated distributed RAM timing in Table 99 and SRL16 timing in Table 100 . Updated global clock timing, removed left/right clock buffer limits in Table 101 . Updated block RAM timing in Table 103 . Added DCM parameters for remainder of Step 0 device; added improved Step 1 DCM performance to Table 104 , Table 105 , Table 106 , and Table 107 . Added minimum INIT_B pulse width specification, T_{INIT} , in Table 111 . Increased data hold time for Slave Parallel mode to 1.0 ns (T_{SMCCD}) in Table 117 . Improved the DCM performance for the XC3S1200E, Stepping 0 in Table 104 , Table 105 , Table 106 , and Table 107 . Corrected links in Table 118 and Table 120 . Added MultiBoot timing specifications to Table 122 .
04/07/06	3.1	Improved SSO limits for LVDS_25, MINI_LVDS_25, and RSDS_25 I/O standards in the QFP packages (Table 97). Removed potentially confusing Note 2 from Table 78 .
05/19/06	3.2	Clarified that 100 mV of hysteresis applies to LVCMOS33 and LVCMOS25 I/O standards (Note 4, Table 80). Other minor edits.
05/30/06	3.2.1	Corrected various typos and incorrect links.
11/09/06	3.4	Improved absolute maximum voltage specifications in Table 73 , providing additional overshoot allowance. Widened the recommended voltage range for PCI and PCI-X standards in Table 80 . Clarified Note 2, Table 83 . Improved various timing specifications for v1.26 speed file. Added Table 85 to summarize the history of speed file releases after which time all devices became Production status. Added absolute minimum values for Table 86 , Table 92 , and Table 93 . Updated pin-to-pin setup and hold timing based on default IFD_DELAY_VALUE settings in Table 87 , Table 88 , and Table 90 . Added Table 89 about source-synchronous input capture sample window. Promoted Module 3 to Production status. Synchronized all modules to v3.4.
03/16/07	3.5	Based on extensive 90 nm production data, improved (reduced) the maximum quiescent current limits for the I_{CCINTQ} , I_{CCAUXQ} , and I_{CCOQ} specifications in Table 79 by an average of 50%.
05/29/07	3.6	Added note to Table 74 and Table 75 regarding HSWAP in step 0 devices. Updated t_{RPW_CLB} in Table 98 to match value in speed file. Improved CLKOUT_FREQ_CLK90 to 200 MHz for Stepping 1 in Table 105 .
04/18/08	3.7	Clarified that Stepping 0 was offered only for -4C and removed Stepping 0 -5 specifications. Added reference to XAPP459 in Table 73 and Table 77 . Improved recommended max V_{CCO} to 3.465V (3.3V + 5%) in Table 77 . Removed minimum input capacitance from Table 78 . Updated Recommended Operating Conditions for LVCMOS and PCI I/O standards in Table 80 . Removed Absolute Minimums from Table 86 , Table 92 and Table 93 and added footnote recommending use of Timing Analyzer for minimum values. Updated T_{PSFD} and T_{PHFD} in Table 87 to match current speed file. Update T_{RPW_IOB} in Table 88 to match current speed file and CLB equivalent spec. Added XC3S500E VQG100 to Table 96 . Replaced $T_{MULCKID}$ with T_{MSCKD} for A, B, and P registers in Table 102 . Updated CLKOUT_PER_JITT_FX in Table 107 . Updated MAX_STEPS equation in Table 109 . Updated Figure 77 and Table 120 to correct CCLK active edge. Updated links.

Package Thermal Characteristics

The power dissipated by an FPGA application has implications on package selection and system design. The power consumed by a Spartan-3E FPGA is reported using either the [XPower Estimator](#) or the [XPower Analyzer](#) calculator integrated in the Xilinx ISE® development software. [Table 130](#) provides the thermal characteristics for the various Spartan-3E package offerings.

The junction-to-case thermal resistance (θ_{JC}) indicates the difference between the temperature measured on the

package body (case) and the die junction temperature per watt of power consumption. The junction-to-board (θ_{JB}) value similarly reports the difference between the board and junction temperature. The junction-to-ambient (θ_{JA}) value reports the temperature difference per watt between the ambient environment and the junction temperature. The θ_{JA} value is reported at different air velocities, measured in linear feet per minute (LFM). The Still Air (0 LFM) column shows the θ_{JA} value in a system without a fan. The thermal resistance drops with increasing air flow.

Table 130: Spartan-3E Package Thermal Characteristics

Device	Package	Junction-to-Case (θ_{JC})	Junction-to-Board (θ_{JB})	Junction-to-Ambient (θ_{JA}) at Different Air Flows				Units
				Still Air (0 LFM)	250 LFM	500 LFM	750 LFM	
XC3S100E	VQ100	13.0	30.9	49.0	40.7	37.9	37.0	°C/Watt
XC3S250E		11.0	25.9	43.3	36.0	33.6	32.7	°C/Watt
XC3S500E		9.8		40.0	33.3	31.0	30.2	°C/Watt
XC3S100E	CP132	19.3	42.0	62.1	55.3	52.8	51.2	°C/Watt
XC3S250E		11.8	28.1	48.3	41.8	39.5	38.0	°C/Watt
XC3S500E		8.5	21.3	41.5	35.2	32.9	31.5	°C/Watt
XC3S100E	TQ144	8.2	31.9	52.1	40.5	34.6	32.5	°C/Watt
XC3S250E		7.2	25.7	37.6	29.2	25.0	23.4	°C/Watt
XC3S250E	PQ208	9.8	29.0	37.0	27.3	24.1	22.4	°C/Watt
XC3S500E		8.5	26.8	36.1	26.6	23.6	21.8	°C/Watt
XC3S250E	FT256	12.4	27.7	35.8	29.3	28.4	28.1	°C/Watt
XC3S500E		9.6	22.2	31.1	25.0	24.0	23.6	°C/Watt
XC3S1200E		6.5	16.4	26.2	20.5	19.3	18.9	°C/Watt
XC3S500E	FG320	9.8	15.6	26.1	20.6	19.4	18.6	°C/Watt
XC3S1200E		8.2	12.5	23.0	17.7	16.4	15.7	°C/Watt
XC3S1600E		7.1	10.6	21.1	15.9	14.6	13.8	°C/Watt
XC3S1200E	FG400	7.5	12.4	22.3	17.2	16.0	15.3	°C/Watt
XC3S1600E		6.0	10.4	20.3	15.2	14.0	13.3	°C/Watt
XC3S1600E	FG484	5.7	9.4	18.8	12.5	11.3	10.8	°C/Watt

TQ144: 144-lead Thin Quad Flat Package

The XC3S100E and the XC3S250E FPGAs are available in the 144-lead thin quad flat package, TQ144. Both devices share a common footprint for this package as shown in [Table 137](#) and [Figure 82](#).

[Table 137](#) lists all the package pins. They are sorted by bank number and then by pin name of the largest device. Pins that form a differential I/O pair appear together in the table. The table also shows the pin number for each pin and the pin type, as defined earlier.

The TQ144 package only supports 20 address output pins in the Byte-wide Peripheral Interface (BPI) configuration mode. In larger packages, there are 24 BPI address outputs.

An electronic version of this package pinout table and footprint diagram is available for download from the Xilinx web site at:

http://www.xilinx.com/support/documentation/data_sheets/s3e_pin.zip

Pinout Table

Table 137: TQ144 Package Pinout

Bank	XC3S100E Pin Name	XC3S250E Pin Name	TQ144 Pin	Type
0	IO	IO	P132	I/O
0	IO/VREF_0	IO/VREF_0	P124	VREF
0	IO_L01N_0	IO_L01N_0	P113	I/O
0	IO_L01P_0	IO_L01P_0	P112	I/O
0	IO_L02N_0	IO_L02N_0	P117	I/O
0	IO_L02P_0	IO_L02P_0	P116	I/O
0	IO_L04N_0/GCLK5	IO_L04N_0/GCLK5	P123	GCLK
0	IO_L04P_0/GCLK4	IO_L04P_0/GCLK4	P122	GCLK
0	IO_L05N_0/GCLK7	IO_L05N_0/GCLK7	P126	GCLK
0	IO_L05P_0/GCLK6	IO_L05P_0/GCLK6	P125	GCLK
0	IO_L07N_0/GCLK11	IO_L07N_0/GCLK11	P131	GCLK
0	IO_L07P_0/GCLK10	IO_L07P_0/GCLK10	P130	GCLK
0	IO_L08N_0/VREF_0	IO_L08N_0/VREF_0	P135	VREF
0	IO_L08P_0	IO_L08P_0	P134	I/O
0	IO_L09N_0	IO_L09N_0	P140	I/O
0	IO_L09P_0	IO_L09P_0	P139	I/O
0	IO_L10N_0/HSWAP	IO_L10N_0/HSWAP	P143	DUAL
0	IO_L10P_0	IO_L10P_0	P142	I/O
0	IP	IP	P111	INPUT
0	IP	IP	P114	INPUT
0	IP	IP	P136	INPUT
0	IP	IP	P141	INPUT
0	IP_L03N_0	IP_L03N_0	P120	INPUT
0	IP_L03P_0	IP_L03P_0	P119	INPUT
0	IP_L06N_0/GCLK9	IP_L06N_0/GCLK9	P129	GCLK
0	IP_L06P_0/GCLK8	IP_L06P_0/GCLK8	P128	GCLK
0	VCCO_0	VCCO_0	P121	VCCO
0	VCCO_0	VCCO_0	P138	VCCO
1	IO/A0	IO/A0	P98	DUAL
1	IO/VREF_1	IO/VREF_1	P83	VREF
1	IO_L01N_1/A15	IO_L01N_1/A15	P75	DUAL
1	IO_L01P_1/A16	IO_L01P_1/A16	P74	DUAL
1	IO_L02N_1/A13	IO_L02N_1/A13	P77	DUAL

User I/Os by Bank

Table 144, Table 145, and Table 146 indicate how the available user-I/O pins are distributed between the four I/O banks on the FT256 package.

The XC3S250E FPGA in the FT256 package has 18 unconnected balls, labeled with an “N.C.” type. These pins are also indicated with the black diamond (◆) symbol in Figure 85.

Table 144: User I/Os Per Bank on XC3S250E in the FT256 Package

Package Edge	I/O Bank	Maximum I/O	All Possible I/O Pins by Type				
			I/O	INPUT	DUAL	VREF ⁽¹⁾	CLK ⁽²⁾
Top	0	44	20	10	1	5	8
Right	1	42	10	7	21	4	0 ⁽²⁾
Bottom	2	44	8	9	24	3	0 ⁽²⁾
Left	3	42	24	7	0	3	8
TOTAL		172	62	33	46	15	16

Notes:

- Some VREF and CLK pins are on INPUT pins.
- The eight global clock pins in this bank have optional functionality during configuration and are counted in the DUAL column.

Table 145: User I/Os Per Bank on XC3S500E in the FT256 Package

Package Edge	I/O Bank	Maximum I/O	All Possible I/O Pins by Type				
			I/O	INPUT	DUAL	VREF ⁽¹⁾	CLK ⁽²⁾
Top	0	46	22	10	1	5	8
Right	1	48	15	7	21	5	0 ⁽²⁾
Bottom	2	48	11	9	24	4	0 ⁽²⁾
Left	3	48	28	7	0	5	8
TOTAL		190	76	33	46	19	16

Notes:

- Some VREF and CLK pins are on INPUT pins.
- The eight global clock pins in this bank have optional functionality during configuration and are counted in the DUAL column.

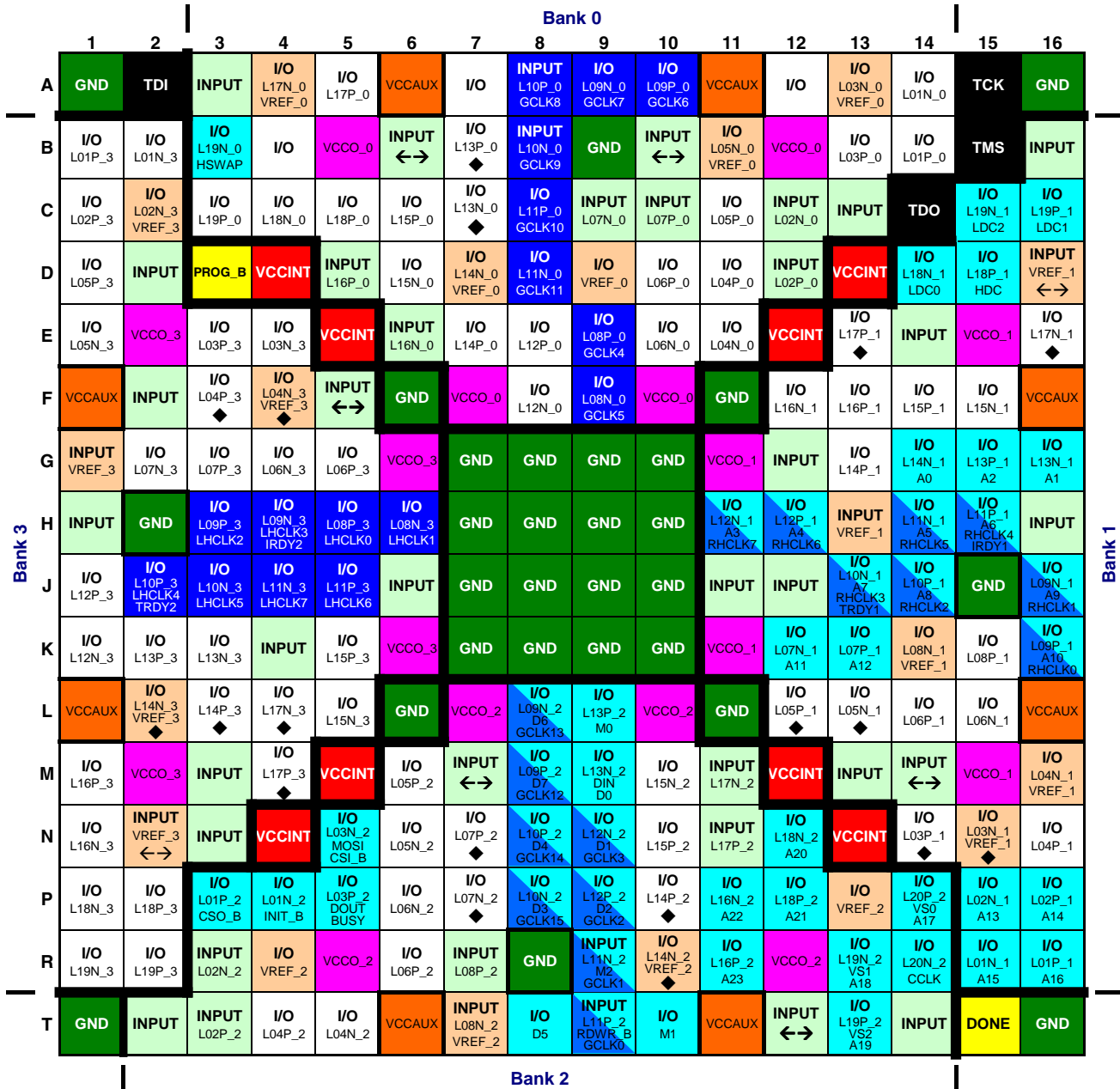
Table 146: User I/Os Per Bank on XC3S1200E in the FT256 Package

Package Edge	I/O Bank	Maximum I/O	All Possible I/O Pins by Type				
			I/O	INPUT	DUAL	VREF ⁽¹⁾	CLK ⁽²⁾
Top	0	46	24	8	1	5	8
Right	1	48	14	8	21	5	0 ⁽²⁾
Bottom	2	48	13	7	24	4	0 ⁽²⁾
Left	3	48	27	8	0	5	8
TOTAL		190	78	31	46	19	16

Notes:

- Some VREF and CLK pins are on INPUT pins.
- The eight global clock pins in this bank have optional functionality during configuration and are counted in the DUAL column.

FT256 Footprint



DS312-4_05_101805

Figure 85: FT256 Package Footprint (top view)

2	CONFIG: Dedicated configuration pins	4	JTAG: Dedicated JTAG port pins	8	VCCINT: Internal core supply voltage (+1.2V)
28	GND: Ground	16	VCCO: Output voltage supply for bank	8	VCCAUX: Auxiliary supply voltage (+2.5V)
6 ↔	Migration Difference: For flexible package migration, use these pins as inputs.	18 (◆)	Unconnected pins on XC3S250E		